

## Features

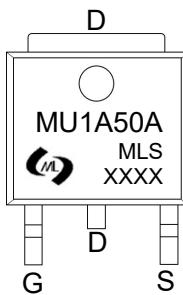
- Super high density cell design for extremely low  $R_{DS(ON)}$
- Exceptional on-resistance and maximum DC current capability

## Product Summary

$V_{DS}$	$R_{DS(ON)}\text{ MAX}$	$I_D\text{ MAX}$
100V	17mΩ@10V	50A

## Application

- Power Management in Note book
- DC/DC Converter
- Load Switch
- LCD Display inverter

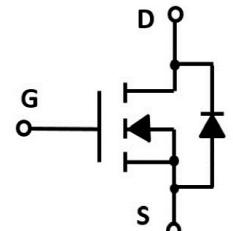


MU1A50A: Device code  
XXXX : Code

Marking and pin assignment



TO-252 top view



Schematic diagram



Halogen-Free

## Absolute Maximum Ratings ( $TA=25^\circ C$ unless otherwise noted)

Symbol	Parameter	Rating	Unit
<b>Common Ratings (<math>TC=25^\circ C</math> Unless Otherwise Noted)</b>			
$V_{DS}$	Drain-Source Breakdown Voltage	100	V
$V_{GS}$	Gate-Source Voltage	$\pm 20$	V
$T_J$	Maximum Junction Temperature	150	°C
$T_{STG}$	Storage Temperature Range	-50 to 155	°C
$I_S$	Diode Continuous Forward Current	50	A
<b>Mounted on Large Heat Sink</b>			
$I_{DM}$	Pulse Drain Current Tested	205	A
$I_D$	Continuous Drain Current	$T_c=25^\circ C$	A
$P_D$	Maximum Power Dissipation	$T_c=25^\circ C$	W
$E_{AS}$	Single pulse Avalanche Energy <sup>Note1</sup>	133	mJ

## Ordering Information (Example)

Type	Package	Marking	Minimum Package(pcs)	Inner Box Quantity(pcs)	Outer Carton Quantity(pcs)	Delivery Mode
MU1A50A	TO-252	MU1A50A	2,500	5,000	35,000	13"reel



**Electrical Characteristics (T<sub>J</sub>=25°C unless otherwise noted)**

Symbol	Parameter	Condition	Min	Typ	Max	Unit
<b>Static Electrical Characteristics @ T<sub>J</sub> = 25°C (unless otherwise stated)</b>						
BV <sub>(BR)DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> =0V, I <sub>D</sub> =250μA	100	--	--	V
I <sub>DSS</sub>	Zero Gate Voltage Drain Current	V <sub>DS</sub> =100V, V <sub>GS</sub> =0V	--	--	1	μA
I <sub>GSS</sub>	Gate-Body Leakage Current	V <sub>GS</sub> =±20V, V <sub>DS</sub> =0V	--	--	±100	nA
V <sub>GS(th)</sub>	Gate Threshold Voltage	V <sub>DS</sub> =V <sub>GS</sub> , I <sub>D</sub> =250μA	2	3	4	V
R <sub>DS(on)</sub>	Drain-Source On-State Resistance	V <sub>GS</sub> =10V, I <sub>D</sub> =20A	--	14	17	mΩ

**Dynamic Electrical Characteristics @ T<sub>J</sub> = 25°C (unless otherwise stated)**

C <sub>ISS</sub>	Input Capacitance	V <sub>DS</sub> =15V, V <sub>GS</sub> =0V, f=1MHz	--	6170	--	pF
C <sub>OSS</sub>	Output Capacitance		--	427	--	pF
C <sub>RSS</sub>	Reverse Transfer Capacitance		--	307	--	pF

**Switching Characteristics**

Q <sub>g</sub>	Total Gate Charge	V <sub>DD</sub> =80V, I <sub>D</sub> =20A, V <sub>GS</sub> =4.5V	--	28	--	nC
Q <sub>gs</sub>	Gate Source Charge		--	28.5	--	nC
Q <sub>gd</sub>	Gate Drain Charge		--	34.5	--	nC
t <sub>d(on)</sub>	Turn-on Delay Time	V <sub>DD</sub> =50V, R <sub>L</sub> =1.8Ω, V <sub>GS</sub> =10V, R <sub>G</sub> =2.5Ω	--	42.5	--	nS
t <sub>r</sub>	Turn-on Rise Time		--	85.7	--	nS
t <sub>d(off)</sub>	Turn-Off Delay Time		--	155	--	nS
t <sub>f</sub>	Turn-Off Fall Time		--	25	--	nS

**Source-Drain Diode Characteristics**

V <sub>SD</sub>	Forward on voltage	T <sub>J</sub> =25°C, I <sub>S</sub> =20A	--	--	1.2	V
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Note :

1、EAS Test condition : V<sub>DS</sub>=100V, V<sub>GS</sub>=20V, L=0.5mH, Starting T<sub>J</sub> = 25°C

### Typical Operating Characteristics

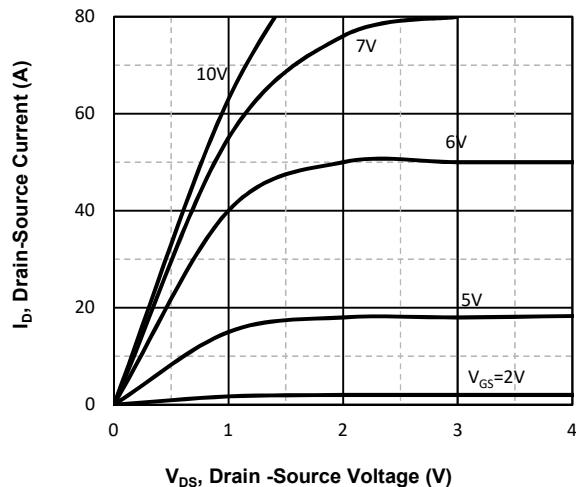


Fig1. Typical Output Characteristics

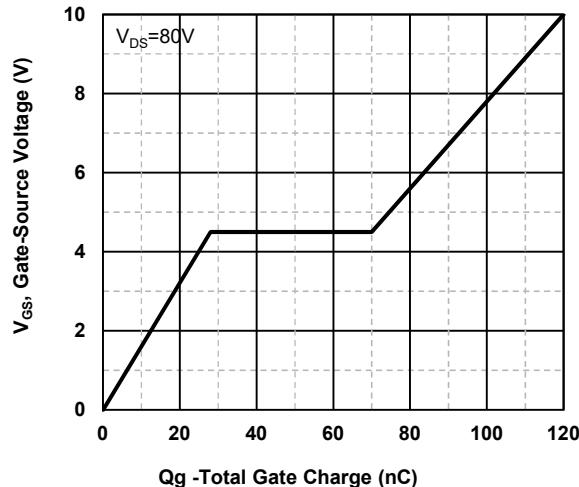


Fig2. Typical Gate Charge Vs.Gate-Source Voltage

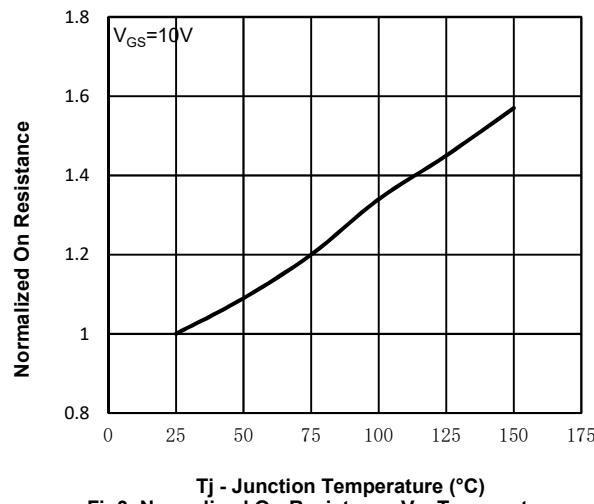


Fig3. Normalized On-Resistance Vs. Temperature

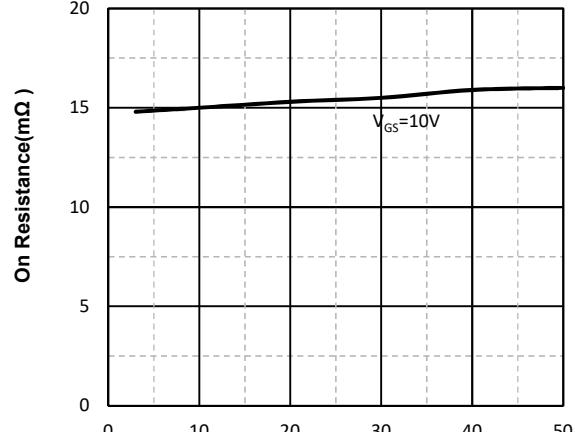


Fig4. On-Resistance Vs. Drain-Source Current

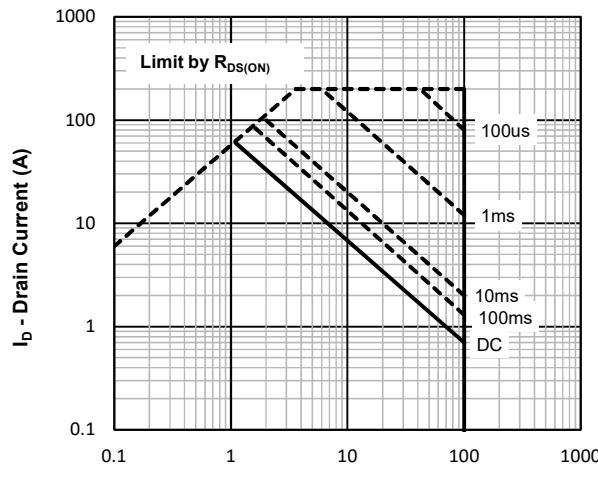


Fig5. Maximum Safe Operating Area

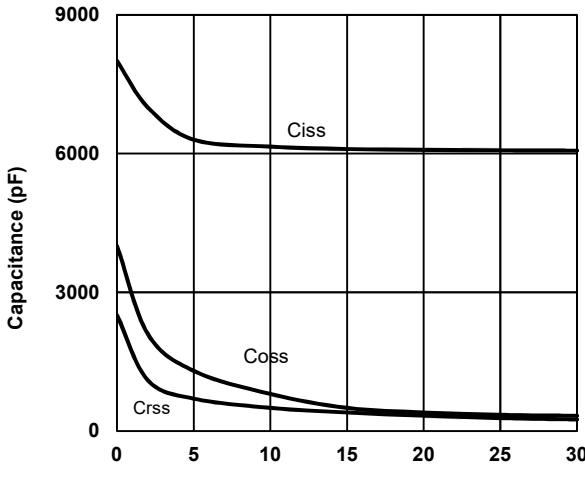
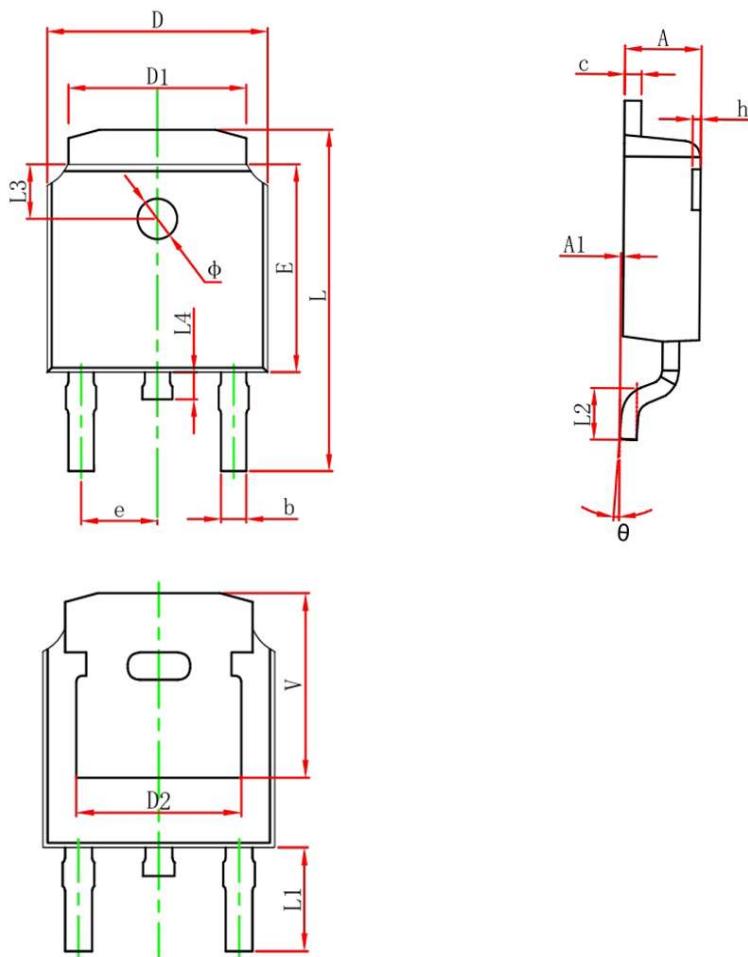


Fig6 Typical Capacitance Vs.Drain-Source Voltage

## TO-252 Package information



Symbol	Dimensions in Millimeters(mm)		Dimensions In Inches	
	Min	Max	Min	Max
A	2.200	2.400	0.087	0.094
A1	0.000	0.127	0.000	0.005
b	0.635	0.770	0.025	0.030
c	0.450	0.580	0.018	0.023
D	6.500	6.700	0.256	0.264
D1	5.100	5.460	0.201	0.215
D2	4.830 REF.		0.190 REF.	
E	6.000	6.200	0.236	0.244
e	2.186	2.386	0.086	0.094
L	9.712	10.312	0.386	0.406
L1	2.900 REF.		0.114 REF.	
L2	1.400	1.700	0.055	0.067
L3	1.600 REF.		0.063 REF.	
L4	0.600	1.000	0.024	0.039
Φ	1.100	1.300	0.043	0.051
θ	0°	8°	0°	8°
h	0.000	0.300	0.000	0.012
V	5.250 REF.		0.207 REF.	